



IPW60R099CP Information



For Reference Only

Part Number IPW60R099CP

Manufacturer Infineon Technologies

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 650V 31A TO-247

TO-247-3 **Package**

For the pricing/inventory/lead time, please contact

Website: https://www.heisener.com

E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









IPW60R099CP Specifications

Manufacturer Part Number	IPW60R099CP
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-247-3
Series	CoolMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	650V
Current - Continuous Drain (Id) @ 25°C	31A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	3.5V @ 1.2mA
Gate Charge (Qg) (Max) @ Vgs	80nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	2800pF @ 100V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	255W (Tc)
Rds On (Max) @ Id, Vgs	99 mOhm @ 18A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	PG-TO247-3
Package / Case	TO-247-3
	Report errors?

IPW60R099CP Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IPW60R099CP Payment Methods



















IPW60R099CP Shipping Methods













If you have any question about IPW60R099CP, please do not hesitate to contact us!

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